

Ho₂Pd_{1.3}Ge_{2.7} – a ternary AlB₂-type cluster glass system

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Supplementary Material

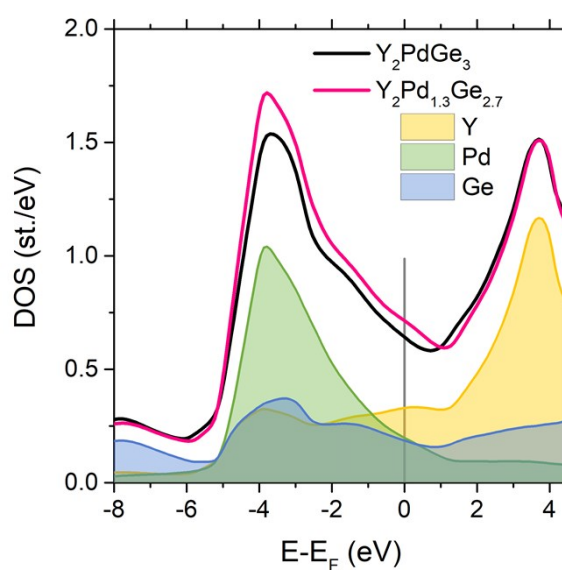
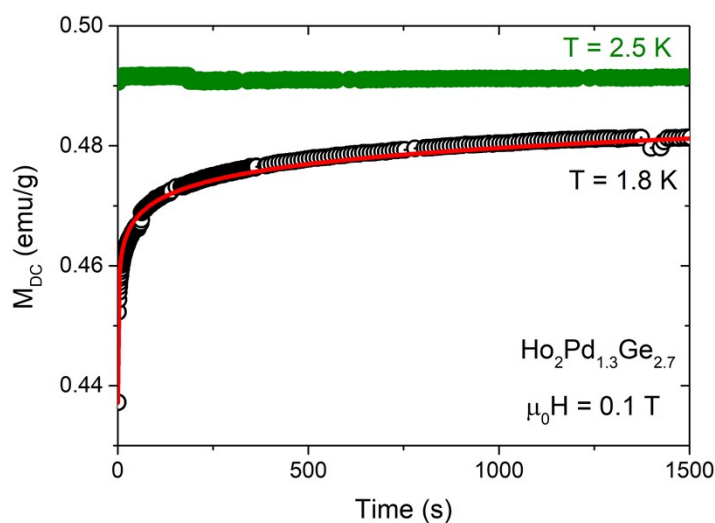


Figure S1: Electronic density of states calculated for Y₂Pd_{1+x}Ge_{3-x} with x = 0 (black line) and 0.3 (pink



line). Substitution of Ge with additional Pd increases slightly the DOS around the Fermi level. The overall shape of the DOS is found to be consistent with a previous report by Sampathkumaran *et al.*¹

Figure S2 Time dependent remnant magnetization behavior for $\text{Ho}_2\text{Pd}_{1.3}\text{Ge}_{2.7}$. Solid red line represents a fit to equation $M(t) = M_0 + S \ln(t/t_0 + 1)$.

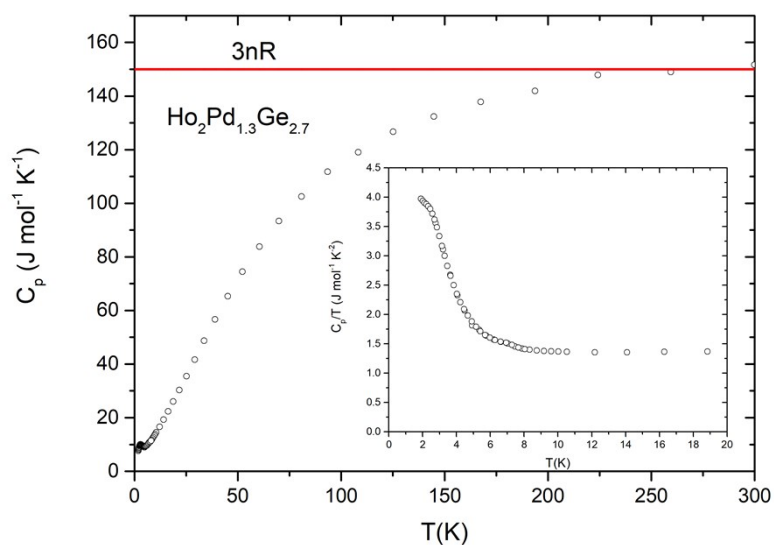


Fig. S3 Temperature dependence of the heat capacity (C_p) for $\text{Ho}_2\text{Pd}_{1.3}\text{Ge}_{2.7}$. Inset shows a plot of C_p/T vs. T at low temperatures measured without applied magnetic field.

Table S1. Results of Rietveld refinement on PXRD data for $\text{Ho}_2\text{Pd}_{1.3}\text{Ge}_{2.7}$

Fit reliability factors				
R_p	10.2%	R_{exp}	4.26%	
R_{wp}	10.8%	χ^2	6.45	
Unit cell parameters (\AA):				
$a =$	4.2379(2)	$c =$	3.8410(3)	
Atomic parameters				
Atom	x	y	z	$B_{\text{iso}} (\text{\AA}^2)$
Ho	0	0	0	1.87(4)
Pd (occ. 0.325) Ge (occ. 0.675)	$1/3$	$2/3$	$1/2$	1.18(4)

References:

- 1 E. V. Sampathkumaran, S. Majumdar, W. Schneider, S. L. Molodtsov and C. Laubschat, Superconductivity in Y_2PdGe_3 , *Phys. B Condens. Matter*, 2002, **312–313**, 152–154.